RT3TLLM

Composite Transistor With Resistor For Switching Application Silicon Epitaxial Type

DESCRIPTION

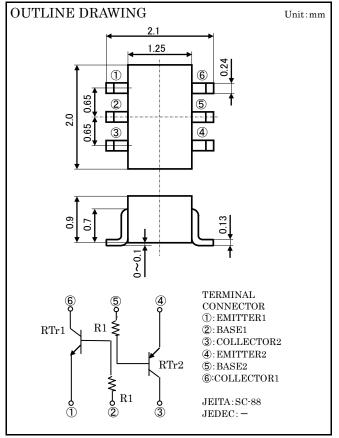
RT3TLLM is composite transistor built with RT1N230 chip and RT1P230 chip in SC-88 package.

FEATURE

Built-in bias resistor (R1=2.2kΩ) Mini package for easy mounting

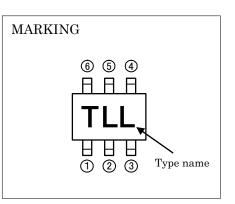
APPLICATION

Inverted circuit, Switching circuit, Interface circuit, Driver circuit



MAXIMUM RATING (Ta=25°C) (RTr1_NPN, RTr2_PNP)

SYMBOL	PARAMETER	RATING	UNIT			
Vcbo	Collector to Base voltage	50	V			
Vebo	Emitter to Base voltage	6	V			
VCEO	Collector to Emitter voltage	50	V			
IC	Collector current	100	mA			
ICM	Peak Collector current	200	mA			
$\mathbf{P}_{\mathbf{T}}$	Total dissipation	200	mW			
Tj	Junction temperature	+150	°C			
Tstg	Storage temperature	-55~+150	°C			
XPNP built in transistor of "-"sign is abbreviation.						

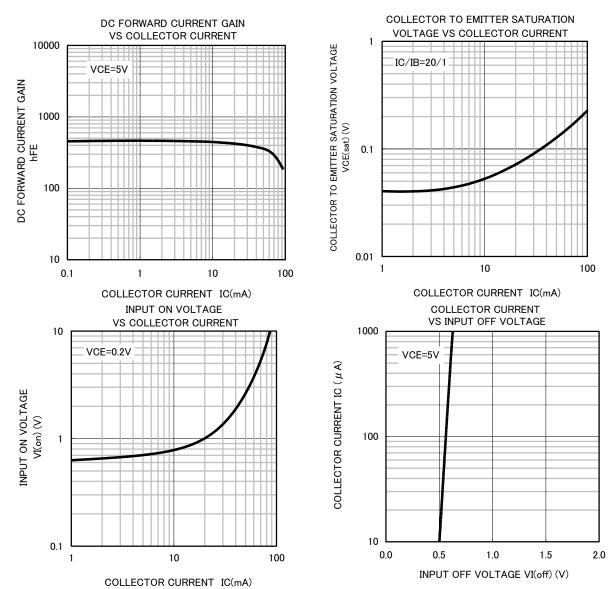


ELECTRICAL CHARACTERISTICS (Ta=25°C) (RTr1_NPN, RTr2_PNP)

0 1 1	Parameter	Test conditions		Limits			TT :
Symbol				Min	Тур	Max	Unit
V(BR)CEO	Collector to Emitter breakdown voltage	$I_{C}=100 \mu$ A, $R_{BE}=\infty$		50	_	—	V
ICBO	Collector cut off current	rrent $V_{CB}=50V$, $I_E=0$		-	_	0.1	μA
IEBO	Emitter cut off current	ent V_{EB} =5V, I _C =0		-	_	0.1	μA
hFE	DC forward current gain V _{CE} =5V, Ic=1mA		100	-	—	—	
VCE(sat)	Collector to Emitter saturation voltage	llector to Emitter saturation voltage Ic=10mA, IB=0.5mA		-	-	0.3	V
R1	Input resistor	_		1.5	2.2	2.9	kΩ
${ m fr}$	Gain band width product	VCE=6V, IE=10mA	RTr1	1	200	_	MIL
			RTr2	-	150	_	MHz

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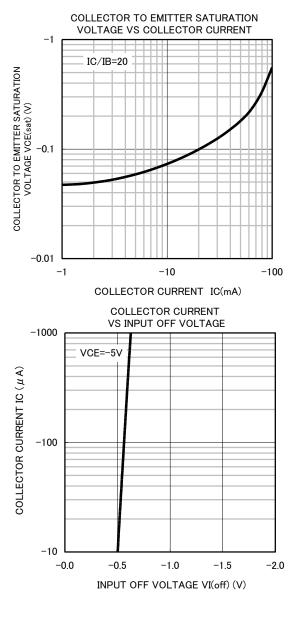
TYPICAL CHARACTERISTICS(Ta=25°C)(RTr1_NPN)

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DC FORWARD CURRENT GAIN VS COLLECTOR CURRENT 10000 VCE=-5V DC FORWARD CURRENT GAIN 1000 НFΕ 100 10 -0.1 -10 -100 -1 COLLECTOR CURRENT IC(mA) INPUT ON VOLTAGE VS COLLECTOR CURRENT -10 VCE=-0.2V INPUT ON VOLTAGE VI(on) (V) -1 -0.1 -1 -10 -100 COLLECTOR CURRENT IC(mA) TOTAL DISSIPATION **VS AMBIENT TEMPERATURE** 300 (MM) TOTAL DISSIPATION PT 00 0 0 25 50 75 100 125 150 AMBIENT TEMPERATURE Ta (°C)

TYPICAL CHARACTERISTICS(Ta=25°C)(RTr 2_PNP)



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